Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass
Overall Length:
Between 0.200 inches and 0.225 inches
Mounting Method:
Compression
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
16.4 breakdown voltage, dc and 15.0 working peak reverse voltage
Current Rating Per Characteristic:
500.00 microamperes forward current, average peak and 63.00 milliamperes forward current, average major
Special Features:
Surface mounted square end cap diodes
Terminal Type And Quantity:
2 bonding pad
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0